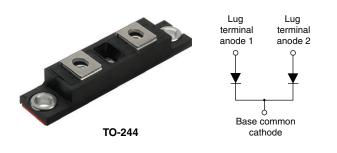
Vishay Semiconductors

High Performance Schottky Rectifier, 200 A



www.vishay.com

PRIMARY CHARACTERISTICS				
I _{F(AV)}	200 A			
V _R	135 V, 150 V			
Package	TO-244			
Circuit configuration	Two diodes common cathode			

FEATURES

- 175 °C T_J operation
- Center tap module
- Low forward voltage drop
- High frequency operation
- Guard ring for enhanced ruggedness and long term reliability
- UL approved file E222165
- · Designed and qualified for industrial level
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

The VS-209CNQ center tap Schottky rectifier module series has been optimized for low reverse leakage at high temperature. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in high current switching power supplies, plating power supplies, UPS systems, converters, freewheeling diodes, welding, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	CHARACTERISTICS VALUES			
I _{F(AV)}	Rectangular waveform	200	А		
V _{RRM}	Range	135/150	V		
I _{FSM}	$t_p = 5 \ \mu s \ sine$	10 000	А		
V _F	100 A _{pk} , T_J = 125 °C (per leg)	0.71	V		
TJ	Range	-55 to +175	°C		

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-209CNQ135PbF	VS-209CNQ150PbF	UNITS	
Maximum DC reverse voltage	V _R	135	150	V	
Maximum working peak reverse voltage	V _{RWM}	155	150	v	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current per leg	1	50 % duty cycle at T_C = 131 °C, rectangular waveform		100	
See fig. 5 per device	IF(AV)			200	
Maximum peak one cycle non-repetitive surge	I _{FSM}	5 µs sine or 3 µs rect. pulse	Following any rated load condition and	10 000	A
current per leg See fig. 7		10 ms sine or 6 ms rect. pulse	with rated V _{RRM} applied	1200	
Non-repetitive avalanche energy per leg	E _{AS}	T _J = 25 °C, I _{AS} = 5.5 A, L = 1 mH		15	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical		1	А

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
	V _{FM} ⁽¹⁾	100 A	T ₁ = 25 °C	1.06	V
Maximum forward voltage drop per leg		200 A	1j=25 0	1.33	
See fig. 1		100 A	T 105 %O	0.74	
		200 A	T _J = 125 °C	0.88	
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	$V_{\rm B} = Rated V_{\rm B}$	3	mA
See fig. 2		T _J = 125 °C	VR - Haleu VR	45	IIIA
Maximum junction capacitance per leg	CT	V_{R} = 5 V_{DC} (test signal range 100 kHz to 1 MHz) 25 $^{\circ}\text{C}$		3000	pF
Typical series inductance per leg	L _S	From top of terminal hole to mounting plane		7.0	nH
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs

Note

⁽¹⁾ Pulse width < 300 μ s, duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS						
PARAMETER		SYMBOL	MIN.	TYP.	MAX.	UNITS
Maximum junction and storage tempera	ture range	T _J , T _{Stg}	-55	-	175	°C
Thermal resistance, junction to case	per leg	Р	-	-	0.38	°C/W
memai resistance, junction to case	per module	R _{thJC}	-	-	0.19	
Thermal resistance, case to heatsink		R _{thCS}	-	0.10	-	
Weight			68		g	
			2.4		oz.	
Mounting torque			35.4 (4)	-	53.1 (6)	
Mounting torque center hole			30 (3.4)	-	40 (4.6)	lbf ⋅ in (N ⋅ m)
Terminal torque			30 (3.4)	- 44.2 (5)		()
Vertical pull 2" lever pull			-	-	80	- lbf ⋅ in
			-	-	35	חו י וטו

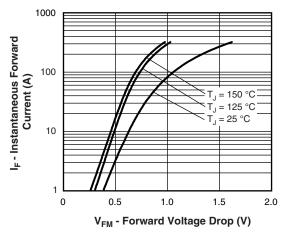


Fig. 1 - Maximum Forward Voltage Drop Characteristics

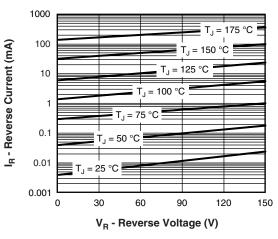


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

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VS-209CNQ...PbF Series

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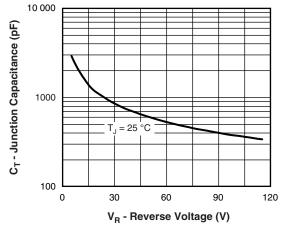


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

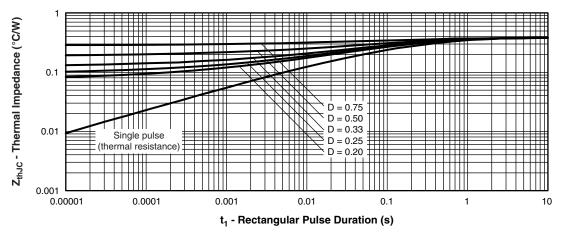
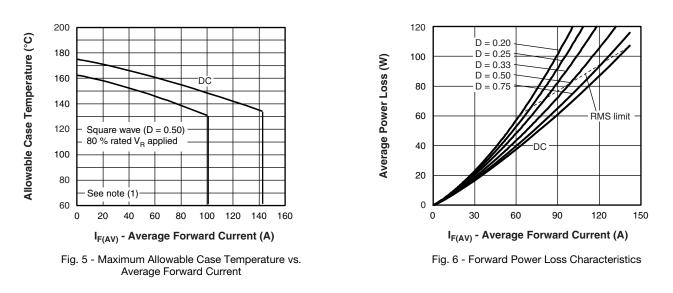


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics



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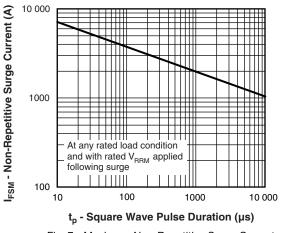
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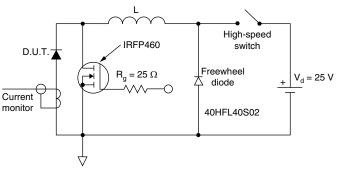
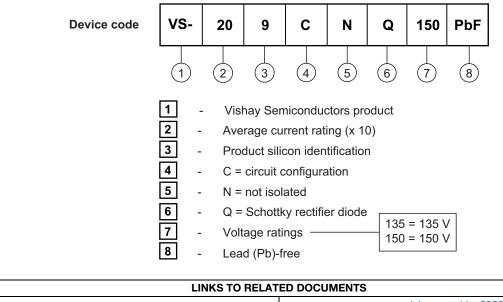


Fig. 8 - Unclamped Inductive Test Circuit

Note

 $\begin{array}{l} \mathsf{Pd} = \mathsf{forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \ \mathsf{x} \ \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{6}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \ \mathsf{x} \ \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \ \mathsf{-D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{80} \ \% \ \mathsf{rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

ORDERING INFORMATION TABLE



LINKS TO RELATED DOCUMENTS					
Dimensions www.vishay.com/doc?95021					

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⁽¹⁾ Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$;

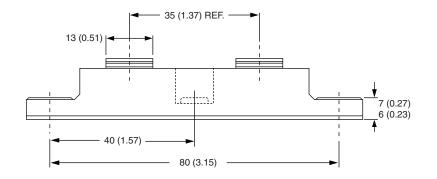


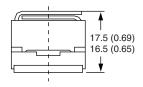


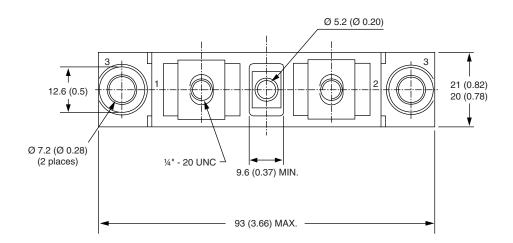
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TO-244

DIMENSIONS in millimeters (inches)









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